

Subscriber Line Interface Circuit

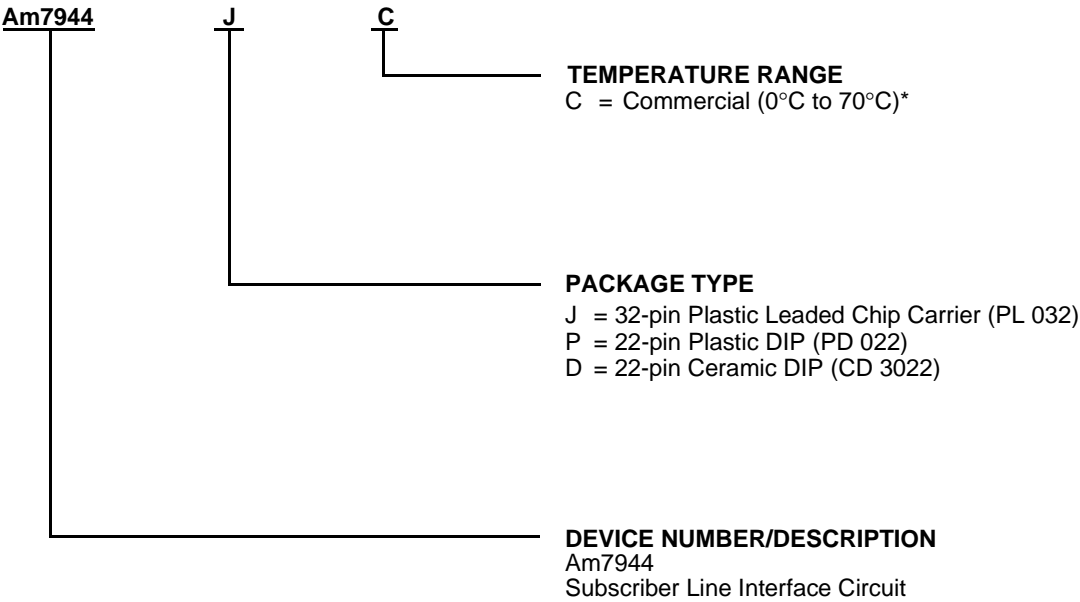
- Programmable constant-current feed
- Current gain = 200
- Programmable loop-detect threshold
- Low standby power
- Ground-key detector
- Tip Open state for ground-start lines
- -19 V to -56.5 V battery operation
- On-chip Thermal Management (TMG) feature
- Two-wire impedance set by single external impedance
- On-hook transmission
- On-chip ring relay driver and relay snubber circuit
- Ideal for DLC, PABX, and Fiber to the Curb/Home applications

The block diagram illustrates the internal architecture of the T1E2000-0100 2-Wire Interface IC. The central component is the **Two-Wire Interface** block, which is connected to the **TMG** (Timing Mark Generator) pin. It interfaces with several external pins: **A(TIP)**, **HPA**, **HPB**, **B(RING)**, **DA**, **DB**, **VBAT**, and **BGND**. The **Two-Wire Interface** block is connected to the **Ground-Key Detector**, **Signal Transmission**, **Off-Hook Detector**, **Power-Feed Controller**, and **Ring-Trip Detector** blocks. The **Ground-Key Detector** is connected to the **Input Decoder and Control** block. The **Signal Transmission** block is connected to the **Ring Relay Driver** and the **Input Decoder and Control** block. The **Off-Hook Detector** is connected to the **Input Decoder and Control** block. The **Power-Feed Controller** is connected to the **Input Decoder and Control** block. The **Ring-Trip Detector** is connected to the **Input Decoder and Control** block. The **Input Decoder and Control** block is connected to the **Ring Relay Driver** and the **Ringout** pin. It also has multiple control pins: **C1**, **C2**, **C3**, **E0**, **E1**, **DET**, **RSN**, **VTX**, **RD**, **RDC**, and **CAS**. The **Ringout** pin is connected to the **Ring Relay Driver**. The **RSN** and **VTX** pins are connected to the **Signal Transmission** block. The **RD**, **RDC**, and **CAS** pins are connected to the **Power-Feed Controller**. The **DET** pin is connected to the **Ground-Key Detector**. The **E0** and **E1** pins are connected to the **Input Decoder and Control** block. The **C1**, **C2**, and **C3** pins are connected to the **Input Decoder and Control** block. The **VBAT** pin is connected to the **Two-Wire Interface** block. The **BGND** pin is connected to ground. The **VCC**, **VEE**, and **AGND/DGND** pins are connected to power and ground planes.

ORDERING INFORMATION

Standard Products

AMD standard products are available in several packages and operating ranges. The order number (Valid Combination) is formed by a combination of the elements below.



Valid Combinations	
Am7944	DC, JC

Valid Combinations

Valid Combinations list configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations, to check on newly released combinations, and to obtain additional data on AMD's standard military grade products.

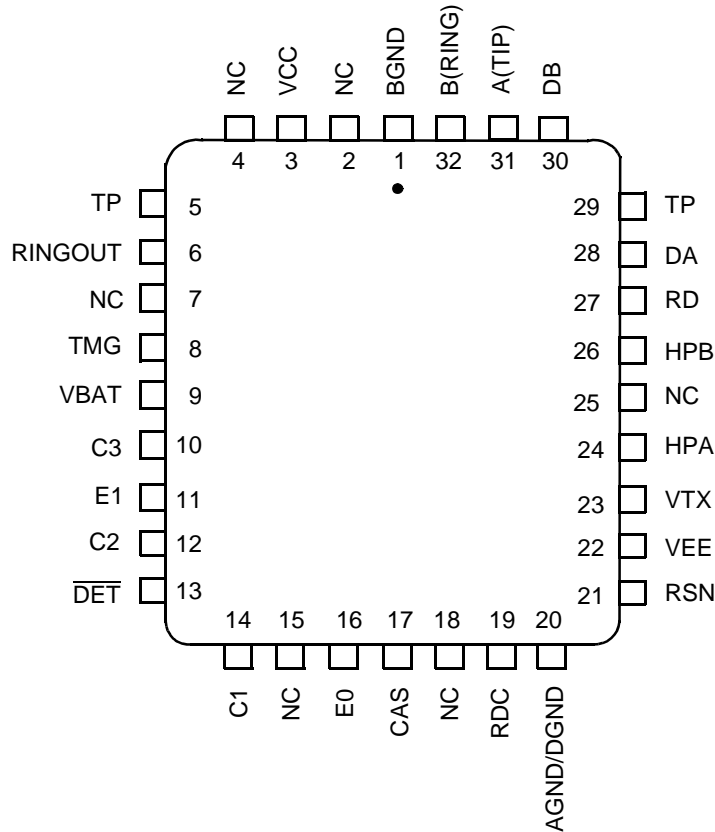
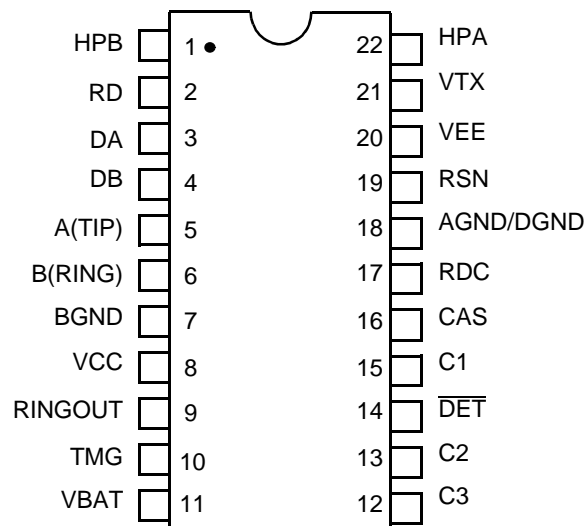
Note:

* Functionality of the device from 0°C to +70°C is guaranteed by production testing. Performance from -40°C to +85°C is guaranteed by characterization and periodic sampling of production units.

CONNECTION DIAGRAMS

Top View

32-Pin PLCC

22-Pin Plastic DIP
or
22-Pin Ceramic DIP**Notes:**

1. Pin 1 is marked for orientation.
2. TP is a thermal conduction pin tied to substrate.
3. NC = No Connect

PIN DESCRIPTIONS

Pin Names	Type	Description
AGND/DGND	Gnd	Analog and Digital ground.
A(TIP)	Output	Output of A(TIP) power amplifier.
BGND	Gnd	Battery (power) ground.
B(RING)	Output	Output of B(RING) power amplifier.
C3–C1	Input	Decoder. TTL compatible. C3 is MSB and C1 is LSB.
CAS	Capacitor	Anti-saturation pin for capacitor to filter reference voltage when operating in anti-saturation region.
DA	Input	Ring-trip negative. Negative input to ring-trip comparator.
DB	Input	Ring-trip positive. Positive input to ring-trip comparator.
$\overline{\text{DET}}$	Output	Switchhook detector. When enabled, a logic Low indicates the selected detector is tripped. The detector is selected by the logic inputs (C3–C1, E1–E0). The output is open-collector with a built-in 15 k Ω pull-up resistor.
E0	Input	$\overline{\text{DET}}$ Enable. A logic High enables $\overline{\text{DET}}$. A logic Low disables $\overline{\text{DET}}$. ($\overline{\text{DET}}$ = Logic High). (PLCC only)
E1	Input	Ground-Key Enable. E1 = High connects the ground-key detector to $\overline{\text{DET}}$. E1 = Low connects the off-hook or ring-trip detector to $\overline{\text{DET}}$. (PLCC only)
HPA	Capacitor	High-Pass Filter Capacitor. A(TIP) side of high-pass filter capacitor.
HPB	Capacitor	High-Pass Filter Capacitor. B(RING) side of high-pass filter capacitor.
RD	Resistor	Detector resistor. Detector threshold set and filter pin.
RDC	Resistor	DC feed resistor. Connection point for the DC feed current programming network. The other end of the network connects to the receiver summing node (RSN). Connection point for the DC feed current programming network. The other end of the network connects to the receiver summing node (RSN). V_{RDC} is negative for normal polarity and positive for reverse polarity.
RINGOUT	Output	Ring Relay Driver. Open-collector driver with emitter internally connected to BGND.
RSN	Input	Receive Summing Node. The metallic current (AC and DC) between A(TIP) and B(RING) is equal to 200 times the current into this pin. The networks that program receive gain, two-wire impedance, and feed current all connect to this node.
TMG	—	Thermal management. A resistor connected from this pin to VBAT reduces the on-chip power dissipation in the normal polarity, Active state only. Refer to Table 2.
TP	Thermal	Thermal pin. Connection for heat dissipation. Internally connected to substrate (VBAT). Leave as open circuit or connected to VBAT. In both cases, the TP pins can connect to an area of copper on the board to enhance heat dissipation
VBAT	Battery	Battery supply.
VCC	Power	+5 V power supply.
VEE	Power	–5 V power supply.
VTX	Output	Transmit Audio. This output is a unity gain version of the A(TIP) and B(RING) metallic voltage. VTX also sources the two-wire input impedance programming network.

ABSOLUTE MAXIMUM RATINGS

Storage temperature	–55°C to +150°C
V _{CC} with respect to AGND/DGND	–0.4 V to +7.0 V
V _{EE} with respect to AGND/DGND	+0.4 V to –7.0 V
V _{BAT} with respect to AGND/DGND:	
Continuous	+0.4 V to –70 V
10 ms	+0.4 V to –75 V
BGND with respect to AGND/DGND	+3 V to –3 V
A(TIP) or B(RING) to BGND:	
Continuous	–70 V to +1 V
10 ms (f = 0.1 Hz)	–70 V to +5 V
1 ms (f = 0.1 Hz)	–80 V to +8 V
10 μs (f = 0.1 Hz)	–100 V to +12 V
Current from A(TIP) or B(RING)	±150 mA
Current from TMG	100 mA
Voltage on RINGOUT:	
During transient	BGND to +10 V
During steady state	BGND to +7 V
Current through relay drivers	60 mA
DA and DB inputs	
Voltage on ring-trip inputs	V _{BAT} to 0 V
Current into ring-trip inputs	±10 mA
C3–C1, E0, E1	
to AGND/DGND	–0.4 V to V _{CC} + 0.4 V
Maximum power dissipation, T _A = 85°C	
No heat sink (See Note):	
In 22-pin ceramic DIP package	1.2 W
In 22-pin plastic DIP package	1.0 W
In 32-pin PLCC package	1.4 W
Thermal data	θ _{JA}
In 22-pin ceramic package	50°C/W typ
In 22-pin plastic package	56°C/W typ
In 32-pin PLCC package	43°C/W typ

Note: Thermal limiting circuitry on chip will shut down the circuit at a junction temperature of about 165°C. The device should never be exposed to this temperature. Operation above 145°C junction temperature may degrade device reliability. See the SLIC Packaging Considerations for more information.

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability.

OPERATING RANGES**Commercial (C) Devices**

Ambient temperature	0°C to +70°C*
V _{CC}	4.75 V to 5.25 V
V _{EE}	–4.75 V to –5.25 V
V _{BAT}	–19 V to –56.5 V
AGND/DGND	0 V
BGND with respect to	
AGND/DGND	–100 mV to +100 mV
Load resistance on VTX to ground	10 kΩ min

Operating Ranges define those limits between which device functionality is guaranteed.

* Functionality of the device from 0°C to +70°C is guaranteed by production testing. Performance from –40°C to +85°C is guaranteed by characterization and periodic sampling of production units.

ELECTRICAL CHARACTERISTICS

The Am7944 device is tested under the following conditions unless otherwise noted: BAT = -48 V, V_{CC} = +5 V, V_{EE} = -5 V, R_L = 900 Ω. The device is not tested in Polarity Reversal state.

Description	Test Conditions (See Note 1)	Min	Typ	Max	Unit	Note	
Analog (V _{TX}) output impedance			3		Ω		
Analog (V _{TX}) output offset	0°C to +70°C −40°C to +85°C	−35 −40		+35 +40	mV	— 4	
Analog (RSN) input impedance	300 Hz to 3.4 kHz		1	20	Ω	4	
Longitudinal impedance at A or B				35			
Overload level	4-wire and 2-wire, Active state	−2.5		+2.5	V _{pk}	2a	
	On hook, R _{LAC} = 900 Ω Active or OHT state	0.95			V _{rms}	2b	
Transmission Performance							
2-wire return loss (See Test Circuit D)	200 to 3400 Hz	26			dB	4, 8	
Longitudinal Balance (2-Wire and 4-Wire, See Test Circuit C); R _L = 740 Ω at V _{BAT} = 48 V							
Longitudinal to metallic L-T, L-4 normal polarity	200 Hz to 1 kHz 0°C to +70°C −40°C to +85°C	63 58			dB	— 4	
	1 kHz to 3.4 kHz 0°C to +70°C −40°C to +85°C	58 54				— 4, 9	
	Longitudinal signal generation 4-L	300 Hz to 800 Hz	42				
	Longitudinal current per pin	Active state and OHT state	27	35			mArms
Insertion Loss (2- to 4-Wire and 4- to 2-Wire, See Test Circuits A and B) BAT = −48 V, R _L = 900 Ω							
Gain accuracy	0 dBm, 1 kHz 0°C to +70°C −40°C to +85°C	−0.15 −0.20		+0.15 +0.20	dB	— 4	
Gain accuracy, OHT state	−10 dBm, on hook, R _{LAC} = 900 Ω	−0.5		+0.5		4	
Variation with frequency	300 Hz to 3.4 kHz relative to 1 kHz 0°C to +70°C −40°C to +85°C	−0.10 −0.15		+0.10 +0.15		4	
Gain tracking	+7 dBm to −55 dBm Reference: 0 dBm −40°C to +85°C	−0.1 −0.15		+0.1 +0.15		4 4	
Balance Return Signal (4- to 4-Wire, See Test Circuit B) BAT = −48 V, R _L = 900 Ω							
Gain accuracy	0 dBm, 1 kHz 0°C to +70°C −40°C to +85°C	−0.15 −0.20		+0.15 +0.20	dB	3 4	
Variation with frequency	300 Hz to 3.4 kHz relative to 1 kHz 0°C to +70°C −40°C to +85°C	−0.1 −0.15		+0.1 +0.15		3 4	
Gain tracking	+3 dBm to −55 dBm Reference: 0 dBm 0°C to +70°C −40°C to +85°C	−0.1 −0.15		+0.1 +0.15		3, 4 4	
Group delay	f = 1 kHz			4		μs	4, 8

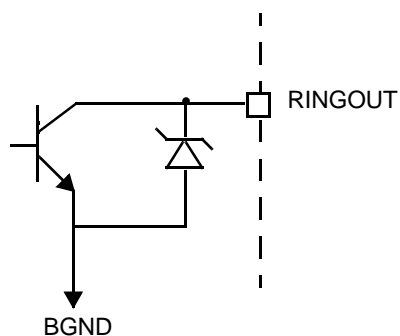
ELECTRICAL CHARACTERISTICS (continued)

Description	Test Conditions (See Note 1)	Min	Typ	Max	Unit	Note
Total Harmonic Distortion (2- to 4-Wire or 4- to 2-Wire, See Test Circuits A and B)						
BAT = −48 V, R _L = 900 Ω						
Harmonic distortion 300 Hz to 3400 Hz	2-wire level = 0 dBm 2-wire level = +7 dBm		−64 −55	−50 −40	dB	
Idle Channel Noise (2-Wire and 4-Wire)						
C-message weighted	2-wire, 0°C to +70°C		+7	+10	dBrnC	4
	2-wire, −40°C to +85°C		+7	+12		4
	4-wire, 0°C to +70°C		+7	+10		4
	4-wire, −40°C to +85°C		+7	+12		4
Psophometric weighted	2-wire, 0°C to +70°C		−83	−80	dBmp	—
	2-wire, −40°C to +85°C		−83	−78		4
	4-wire, 0°C to +70°C		−83	−80		—
	4-wire, −40°C to +85°C		−83	−78		4
Line Characteristics, Active State (See Figure 1)						
Short loops, Active state	BAT = −48 V, R _{LDC} = 600 Ω	25.0	27.0	29.0	mA	
Long loops, Active state	BAT = −48 V, R _{LDC} = 1.9 kΩ	18.0	20.4			
OHT state	BAT = −48 V, R _{LDC} = 600 Ω	16.0	18.0	20.0		
Standby state	$I_L = \frac{ V_{BAT} - 3 \text{ V}}{R_L + 1800}, T_A = 25^\circ\text{C}$	0.7I _L	I _L	1.3I _L		
	R _L = 600 Ω, BAT = −48 V T _A = 70°C	15.0	17.4			
Loop current	Tip Open state, R _L = 0			100	μA	
	Disconnect state, R _L = 0			100		
	Tip Open state, Bwire to GND	22	30	44	mA	
	Tip Open state, Bwire = V _{BAT} + 6 V	20	30	45		
I _L LIM (I _{TIP} + I _{RING})	Tip and ring shorted to GND		100	130		
Ground-start signaling (tip voltage)	Active state R _{TIP} to −48 V = 7.0 kΩ R _{RING} to GND = 100 Ω	−7.5	−5.0		V	
Open circuit voltage	Active and OHT states BAT = −48 V	40.5	42.0			
Power Dissipation, BAT = −48 V						
On hook, Open Circuit state			25	70	mW	
On hook, OHT state			120	210		
On hook, Active state	R _{TMG} = Open R _{TMG} = 1700 Ω		160 195	230 280		
On hook, Standby state			35	85		
Off hook, OHT state	R _L = 300 Ω, R _{TMG} = ∞ BAT = −48 V		735	1050		
Off hook, Active state	R _L = 300 Ω, R _{TMG} = ∞ BAT = −48 V		1.25	1.45	W	
	R _L = 300 Ω, R _{TMG} = ∞		0.57	0.85		
Off hook, Standby state	R _L = 600 Ω, T _A = 25°C		0.68	1.0		

ELECTRICAL CHARACTERISTICS (continued)

Description	Test Conditions (See Note 1)	Min	Typ	Max	Unit	Note		
Supply Currents, BAT = −48 V								
V _{CC} on-hook supply current	Open Circuit state OHT state Standby state Active state		1.7 4.9 2.2 6.3	2.5 7.5 3.0 8.5	mA			
V _{EE} on-hook supply current	Open Circuit state OHT state Standby state Active state		0.7 2.0 0.77 2.1	2.0 3.5 2.0 5.0				
V _{BAT} on-hook supply current	Open Circuit state OHT state Standby state Active state		0.18 1.9 0.45 4.2	1.0 4.7 1.5 5.7				
Power Supply Rejection Ratio (V _{RIPPLE} = 50 mVrms), Active Normal State								
V _{CC}	50 Hz to 3.4 kHz	33	40				dB	5
V _{EE}	50 Hz to 3.4 kHz	29	35					
V _{BAT}	50 Hz to 3.4 kHz	30	50					
Effective internal resistance	CAS pin to GND	85	170	255	kΩ	4		
RFI rejection	100 Hz to 30 MHz (See Figure E)			1.0	mVrms	4		
Off-Hook Detector								
Current threshold	I _{DET} = $\frac{375}{R_D}$	−10		+10	%			
Ground-Key Detector Thresholds, Active State, BAT = −48 V								
Ground-key resistance threshold	B(RING) to GND	2.0	5.0	10.0	kΩ			
Ground-key current threshold	B(RING) to GND		9.0		mA			
Ring-Trip Detector Input								
Bias current		−0.5	−0.05		μA			
Offset voltage	Source resistance = 2 MΩ	−50	0	+50	mV	6		
Logic Inputs C3–C1, E0, E1								
Input High voltage		2.0			V			
Input Low voltage				0.8				
Input High current	All inputs except C3 and E1 Input C3 Input E1	−75 −75 −75		40 200 45	μA			
Input Low current		−0.4			mA			
Logic Output (DET)								
Output Low voltage	I _{OUT} = 0.8 mA			0.4	V			
Output High voltage	I _{OUT} = −0.1 mA	2.4						
Relay Driver Output (RINGOUT)								
On voltage	35 mA sink		+0.25	+0.4	V			
Off leakage	V _{OH} = +5 V			100	μA			
Zener breakover	100 μA	6	7.2		V			
Zener On voltage	30 mA		10					

RELAY DRIVER SCHEMATIC



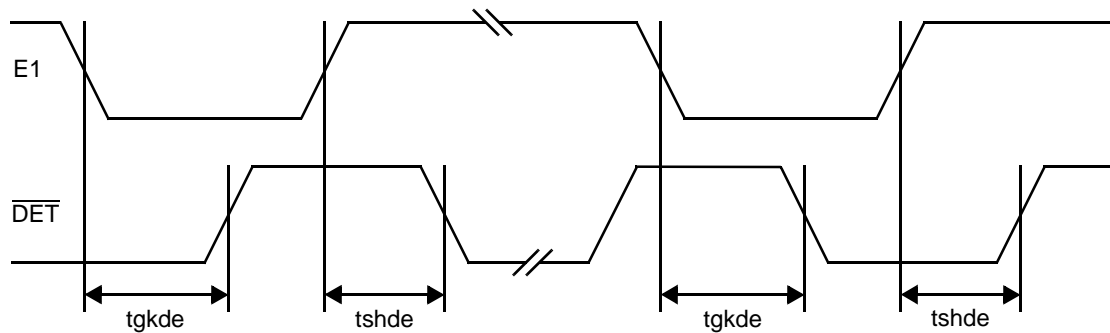
SWITCHING CHARACTERISTICS

(32-pin PLCC only)

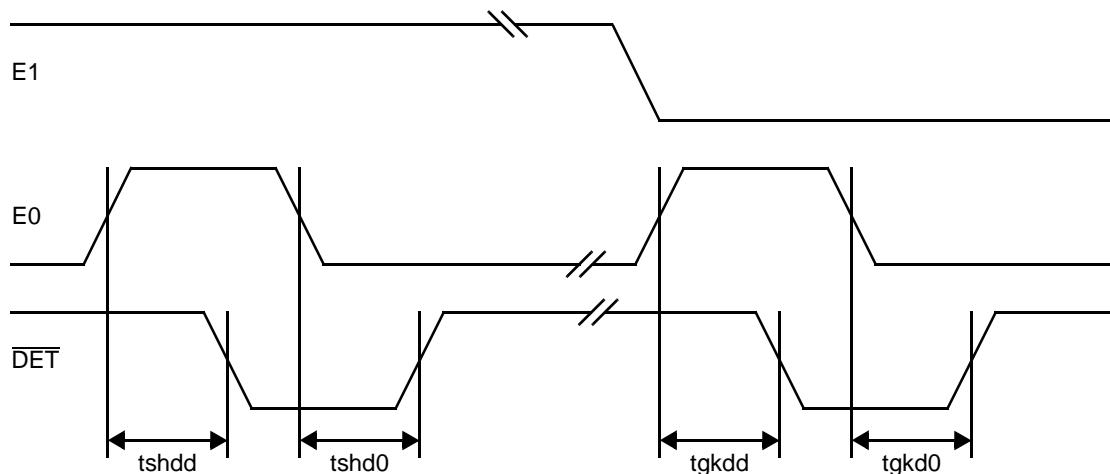
Symbol	Parameter	Test Conditions	Temperature Ranges	Min	Typ	Max	Unit	Note
tgkde	E1 Low to $\overline{\text{DET}}$ High (E0 = 1)	Ground-Key Detect state R_L open, R_G connected (See Figure H)	0°C to 70°C			3.8	μs	4
	E1 Low to $\overline{\text{DET}}$ Low (E0 = 1)		–40°C to +85°C			4.0		
tgkdd	E0 High to $\overline{\text{DET}}$ Low (E1 = 0)		0°C to 70°C			1.1		
			–40°C to +85°C			1.6		
tgkd0	E0 Low to $\overline{\text{DET}}$ High (E1 = 0)		0°C to 70°C			3.8		
			–40°C to +85°C			4.0		
tshde	E1 High to $\overline{\text{DET}}$ Low (E0 = 1)	Switchhook Detect state $R_L = 600\ \Omega$, R_G open (See Figure G)	0°C to 70°C			1.2	μs	4
	E1 High to $\overline{\text{DET}}$ High (E0 = 1)		–40°C to +85°C			1.7		
			0°C to 70°C			3.8		
			–40°C to +85°C			4.0		
tshdd	E0 High to $\overline{\text{DET}}$ Low (E1 = 1)		0°C to 70°C			1.1		
			–40°C to +85°C			1.6		
tshd0	E0 Low to $\overline{\text{DET}}$ High (E1 = 1)		0°C to 70°C			3.8		
			–40°C to +85°C			4.0		

SWITCHING WAVEFORMS

E1 to $\overline{\text{DET}}$



E0 to $\overline{\text{DET}}$

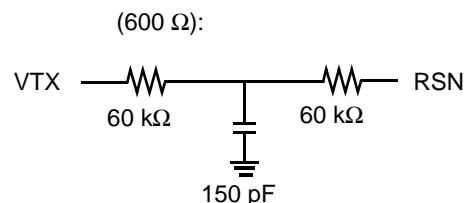
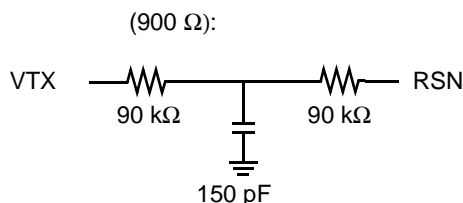


Note:

All delays measured at 1.4 V level.

Notes:

1. Unless otherwise noted, test conditions are $V_{CC} = +5\text{ V}$, $V_{EE} = -5\text{ V}$, $C_{HP} = 0.33\text{ }\mu\text{F}$, $R_{DC1} = R_{DC2} = 9.26\text{ k}\Omega$, $C_{DC} = 0.33\text{ }\mu\text{F}$, $R_D = 35.4\text{ k}\Omega$, $C_{CAS} = 0.33\text{ }\mu\text{F}$, no fuse resistors, $BAT = -48\text{ V}$, $R_L = 900\text{ }\Omega$, and $R_{TMG} = 1700\text{ }\Omega$.
2. a. Overload level is defined when $\text{THD} = 1\%$.
b. Overload level is defined when $\text{THD} = 1.5\%$
3. Balance return signal is the signal generated at V_{TX} by V_{RX} . This specification assumes the two-wire AC load impedance matches the programmed impedance.
4. Not tested in production. This parameter is guaranteed by characterization or correlation to other tests.
5. This parameter is tested at 1 kHz with a termination impedance of $900\text{ }\Omega$ and an R_L of $600\text{ }\Omega$ in production. Performance at other frequencies is guaranteed by characterization.
6. Tested with $0\text{ }\Omega$ source impedance. $2\text{ M}\Omega$ is specified for system design only.
7. Assumes the following Z_T networks:



8. Group delay can be considerably reduced by using a Z_T network such as that shown in Note 7 above. The network reduces the group delay to less than $2\text{ }\mu\text{s}$. The effect of group delay on the linecard performance may be compensated for by using the QSLAC™ or DSLAC™ device.

Table 1. SLIC Decoding

State	C3	C2	C1	Two-Wire Status	DET Output	
					E1 = 1	E1 = 0
0	0	0	0	Open Circuit	Ring trip	Ring trip
1	0	0	1	Ringing	Ring trip	Ring trip
2	0	1	0	Active	Loop detector	Ground key
3	0	1	1	On-Hook TX (OHT)	Loop detector	Ground key
4	1	0	0	Tip Open	Loop detector	Ground key
5	1	0	1	Standby	Loop detector	Ground key
6	1	1	0	Reserved		
7	1	1	1	Reserved		

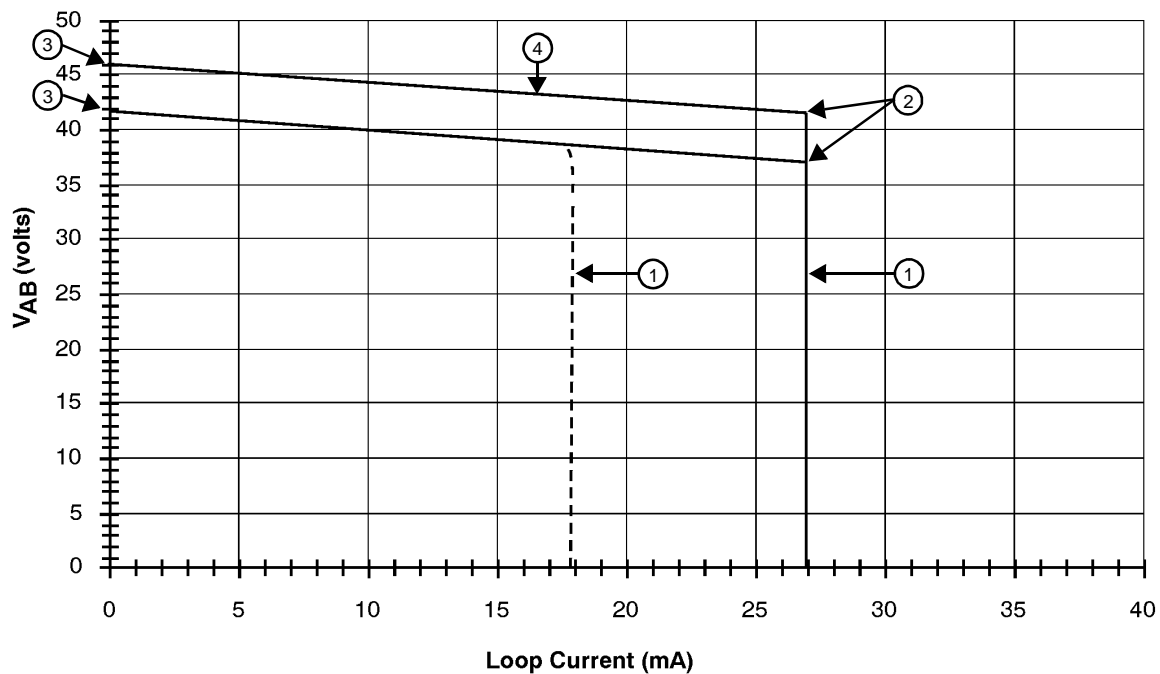
Note:

E0 and E1 are internally pulled High in the 22-pin DIP package option. E0 High enables the $\overline{\text{DET}}$ pin.

Table 1. User-Programmable Components

$Z_T = 200(Z_{2\text{WIN}} - 2R_F)$	Z_T is connected between the VTX and RSN pins. The fuse resistors are R_F , and $Z_{2\text{WIN}}$ is the desired 2-wire AC input impedance. When computing Z_T , the internal current amplifier pole and any external stray capacitance between VTX and RSN must be taken into account.
$Z_{RX} = \frac{Z_L}{G_{42L}} \cdot \frac{500 \cdot Z_T}{Z_T + 200(Z_L + 2R_F)}$	Z_{RX} is connected from V_{RX} to R_{SN} . Z_T is defined above, and G_{42L} is the desired receive gain.
$R_{DC1} + R_{DC2} = \frac{500}{I_{\text{LOOP}}}$ $C_{DC} = 1.5 \text{ ms} \cdot \frac{R_{DC1} + R_{DC2}}{R_{DC1} \cdot R_{DC2}}$	R_{DC1} , R_{DC2} , and C_{DC} form the network connected to the RDC pin. R_{DC1} and R_{DC2} are approximately equal. I_{LOOP} is the desired loop current in the constant-current region.
$R_D = \frac{375}{I_T}, \quad C_D = \frac{0.5 \text{ ms}}{R_D}$	R_D and C_D form the network connected from RD to -5 V and I_T is the threshold current between on hook and off hook.
$I_{\text{OHT}} = \frac{500 \text{ V} \cdot 0.66}{R_{DC1} + R_{DC2}}$	OHT loop current (constant-current region).
$C_{\text{CAS}} = \frac{1}{3.4 \cdot 10^5 \pi f_c}$	C_{CAS} is the filter regulator filter capacitor and f_c is the desired filter cutoff frequency.
Thermal Management Equations (Normal Active and Tip Open States)	
$R_{\text{TMG}} \geq \frac{V_{\text{BAT}} - 6 \text{ V}}{I_{\text{LOOP}}}$	R_{TMG} is connected from T_{MG} to V_{BAT} and is used to limit power dissipation within the SLIC in Normal Active and Tip Open states only.
$P_{\text{RTMG}} = \frac{(V_{\text{BAT}} - 6 \text{ V} - (I_L \cdot R_L))^2}{R_{\text{TMG}}}$	Power dissipated in the thermal management resistor, R_{TMG} , during Active and Tip Open states.
$P_{\text{SLIC}} = V_{\text{BAT}} \cdot I_L - P_{\text{RTMG}} - R_L(I_L)^2 + 0.12 \text{ W}$	Power dissipated in the SLIC while in Active and Tip Open states.

DC FEED CHARACTERISTICS



$$R_{DC1} + R_{DC2} = R_{DC} = 18.52 \text{ k}\Omega$$

———— Active state

----- OHT state

Notes:

1. Constant-current region:

$$\text{Active state, } I_L = \frac{500}{R_{DC}}$$

$$\text{OHT state, } I_L = \frac{2}{3} \cdot \frac{500}{R_{DC}}$$

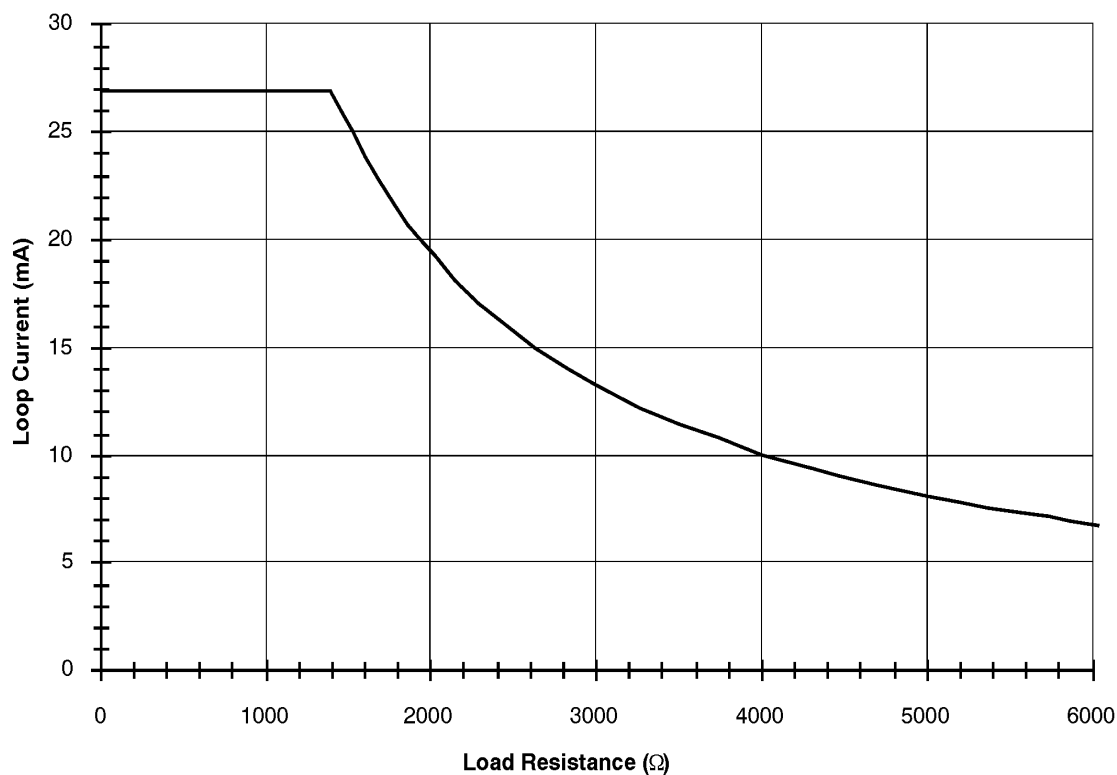
$$2. \text{ Anti-sat (battery tracking) turn-on: } V_{AB} = 1.017|V_{BAT}| - 10.7$$

$$3. \text{ Open circuit voltage: } V_{AB} = 1.017|V_{BAT}| - 6.3$$

$$4. \text{ Anti-sat (battery tracking) region: } V_{AB} = 1.017|V_{BAT}| - 6.3 - I_L \frac{R_{DC}}{120}$$

a. V_A–V_B (V_{AB}) Voltage vs. Loop Current (Typical)

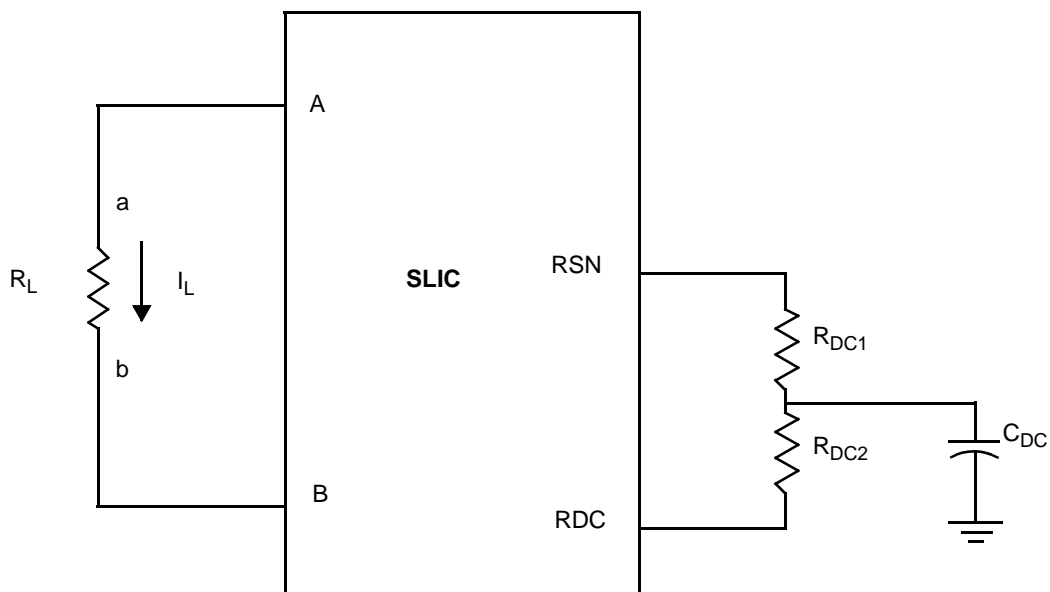
DC FEED CHARACTERISTICS (continued)



$$R_{DC1} + R_{DC2} = R_{DC} = 18.52 \text{ k}\Omega$$

$$V_{BAT} = 47.3 \text{ V}$$

b. Loop Current vs. Load Resistance (Typical)

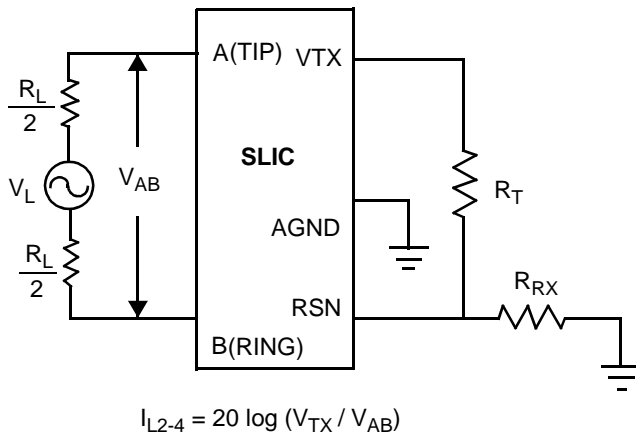


Feed current programmed by R_{DC1} and R_{DC2}

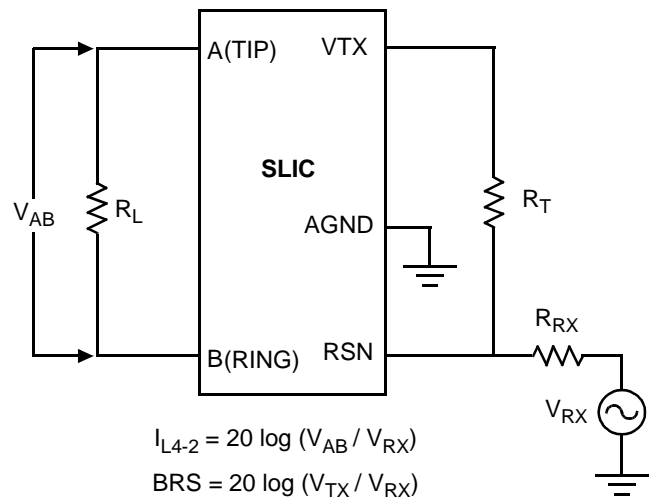
c. Feed Programming

Figure 1. DC Feed Characteristics

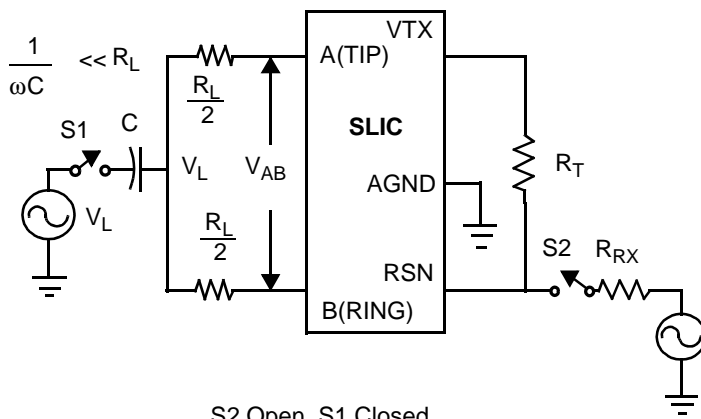
TEST CIRCUITS



A. Two- to Four-Wire Insertion Loss

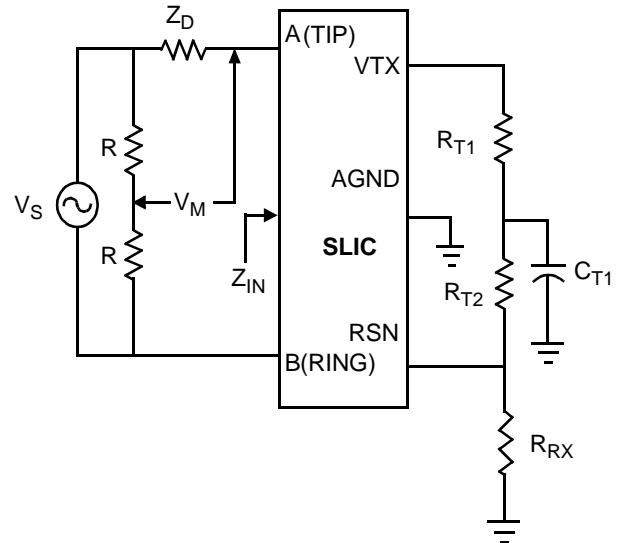


B. Four- to Two-Wire Insertion Loss and Balance Return Signal



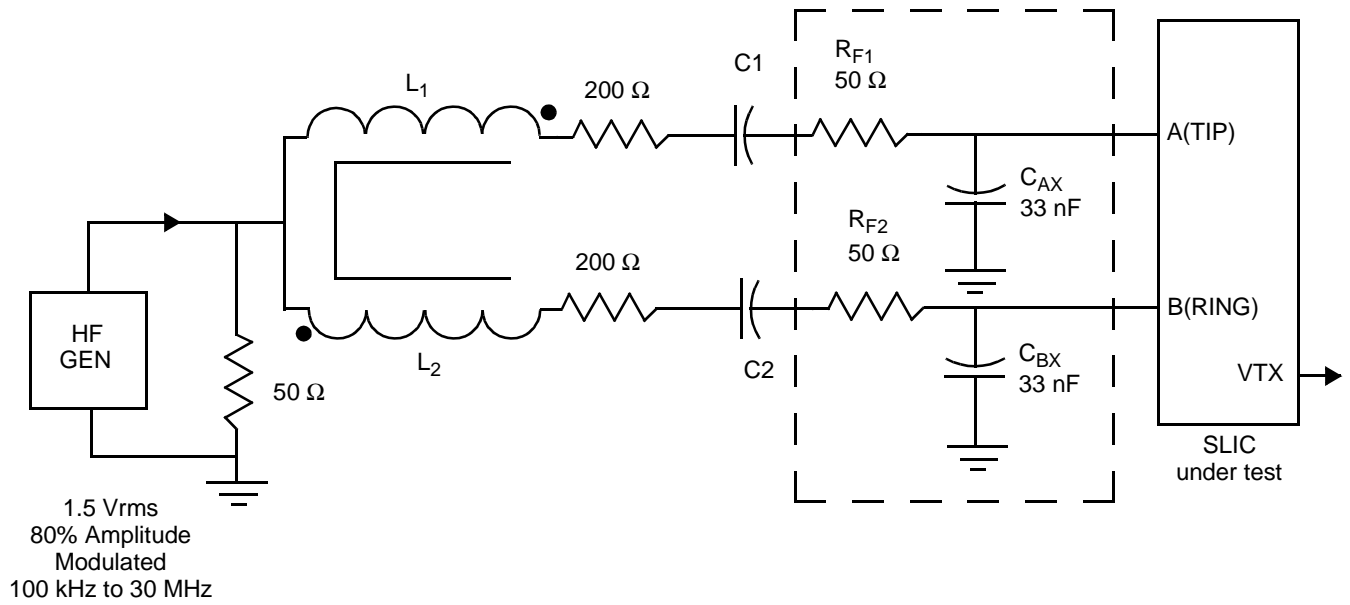
S2 Closed, S1 Open
 $4-L \text{ Long. Sig. Gen.} = 20 \log (V_L / V_{RX})$

C. Longitudinal Balance

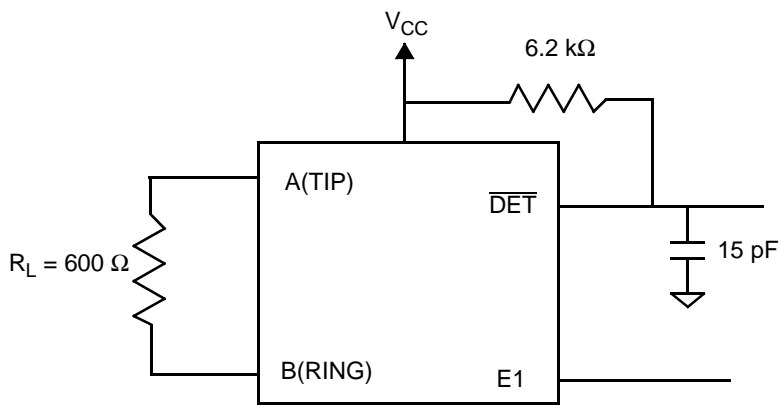


D. Two-Wire Return Loss Test Circuit

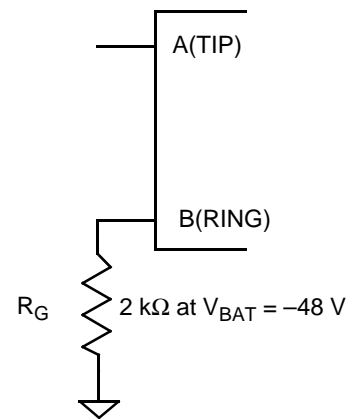
TEST CIRCUITS (continued)



E. RFI Test Circuit

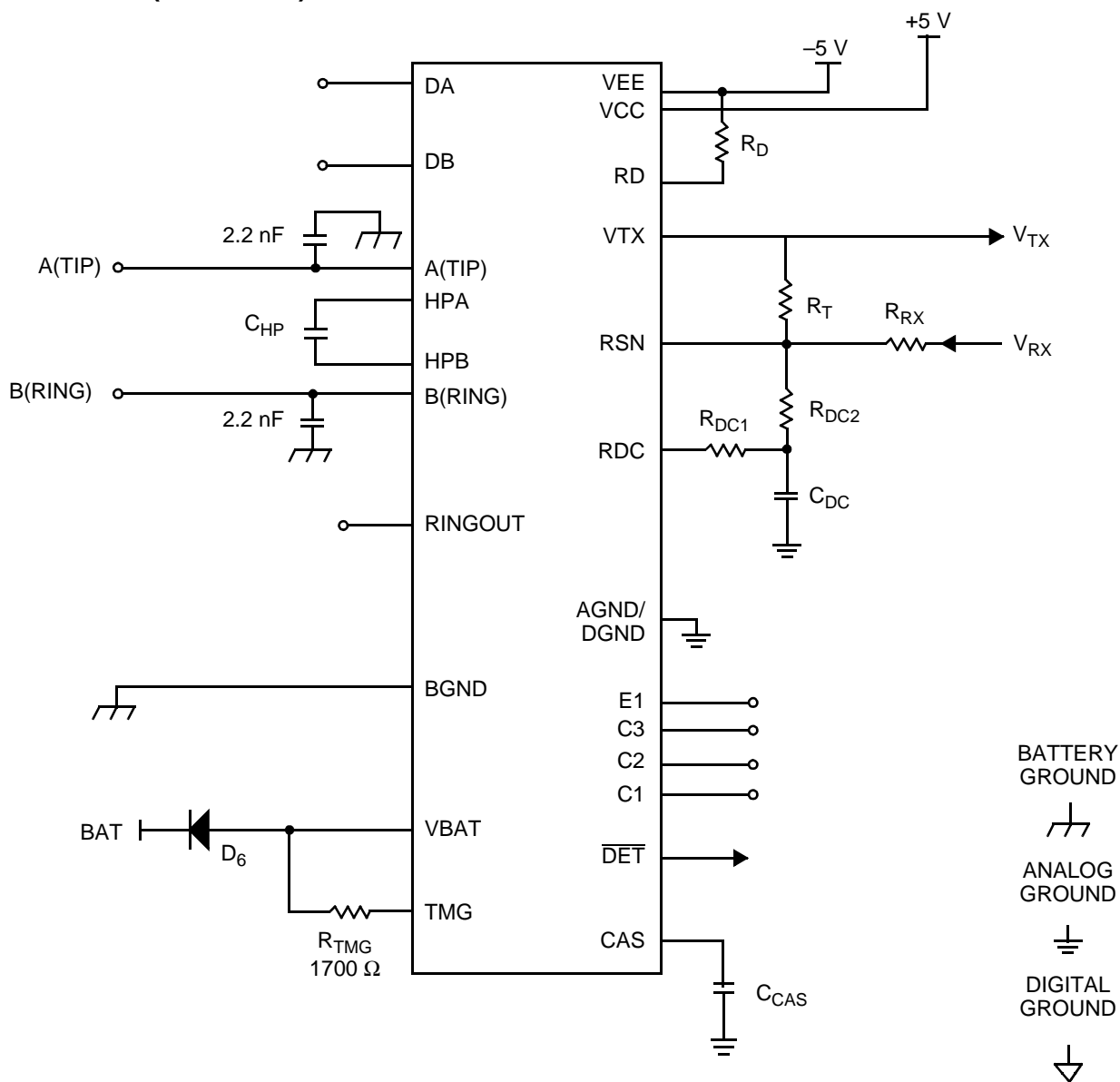


F. Loop-Detector Switching



G. Ground-Key Switching

TEST CIRCUITS (continued)



REVISION SUMMARY

Revision A to B

- Minor changes were made to the data sheet style and format to conform to AMD standards.

Revision B to Revision C

- In Pin Description table, inserted/changed TP pin description to: "Thermal pin. Connection for heat dissipation. Internally connected to substrate (QBAT). Leave as open circuit or connected to QBAT. In both cases, the TP pins can connect to an area of copper on the board to enhance heat dissipation."
- Minor changes were made to the data sheet style and format to conform to AMD standards.

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